CMOS Quad 3-State R/S Latches

High-Voltage Types (20-Volt Rating)
Quad NOR R/S Latch – CD4043B
Quad NAND R/S Latch – CD4044B

■CD4043B types are quad cross-coupled 3-state CMOS NOR latches and the CD4044B types are quad cross-coupled 3-state CMOS NAND latches. Each latch has a separate Q output and individual SET and RESET inputs. The Q outputs are controlled by a common ENABLE input. A logic "1" or high on the ENABLE input connects the latch states to the Q outputs. A logic "0" or low on the ENABLE input disconnects the latch states from the Q outputs, resulting in an open circuit condition on the Q outputs. The open circuit feature allows common bussing of the outputs.

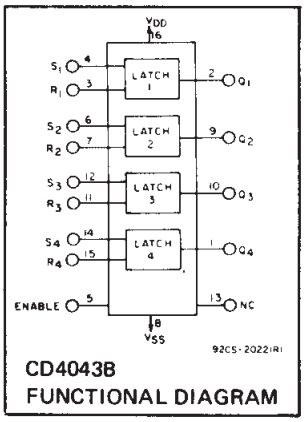
The CD4043B and CD4044B types are supplied in 16-lead hermetic dual-in-line ceramic packages (F3A suffix), 16-lead dual-in-line plastic packages (E suffix), 16-lead small-outline packages (D, DR, DT, DW, DWR, and NSR suffixes), and 16-lead thin shrink small-outline packages (PW and PWR suffixes).

Features:

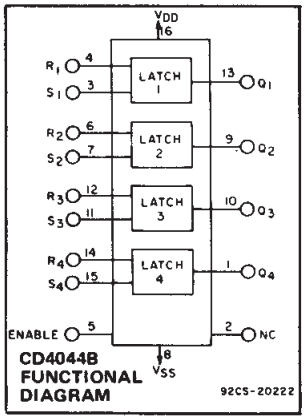
- 3-state outputs with common output ENABLE
- Separate SET and RESET inputs for each latch
- NOR and NAND configurations
- 5-V, 10-V, and 15-V parametric ratings
- Standardized symmetrical output characteristics
- 100% tested for quiescent current at 20 V
- Maximum input current of 1 μA at 18 V over full package temperature range; 100 nA at 18 V and 25°C
- Noise margin (over full package temperature range): 1 V at V_{DD} = 5 V; 2 V at V_{DD} = 10 V; 2.5 V at V_{DD} = 15 V
- Meets all requirements of JEDEC Tentative Standard No. 13B, "Standard Specifications for Description of 'B' Series CMOS Devices"

Applications:

- Holding register in multi-register system
- Four bits of independent storage with output ENABLE
- Strobed register
- General digital logic
- CD4043B for positive logic systems
- CD4044B for negative logic systems



CD4043B FUNCTIONAL DIAGRAM



CD4044B FUNCTIONAL DIAGRAM

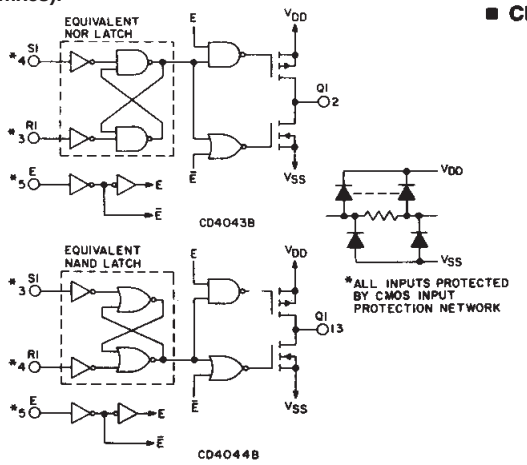
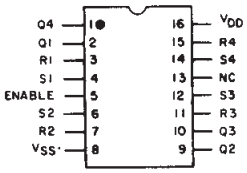
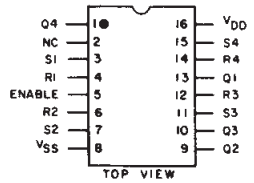


Fig. 1 – Logic diagrams.



NC = NO CONNECTION

CD4043B



NC = NO CONNECTION

CD4044B

TERMINAL ASSIGNMENTS

S	R	E	Q
X	X	0	OC*
0	0	1	NC+
1	0	1	1
0	1	1	0
1	1	1	Δ

*OPEN CIRCUIT
+NO CHANGE
Δ DOMINATED BY S=1 INPUT

CD4043B

S	R	E	Q
X	X	0	OC*
1	1	1	NC+
0	1	1	1
1	0	1	0
0	0	1	ΔΔ

*OPEN CIRCUIT
+NO CHANGE
ΔΔ DOMINATED BY R=0 INPUT

CD4044B

MAXIMUM RATINGS, *Absolute-Maximum Values:*

DC SUPPLY-VOLTAGE RANGE, (V_{DD})
(Voltages referenced to V_{SS} Terminal) ..... -0.5V to +20V
INPUT VOLTAGE RANGE, ALL INPUTS ..... -0.5V to V_{DD} +0.5V
DC INPUT CURRENT, ANY ONE INPUT ..... ±10mA
POWER DISSIPATION PER PACKAGE (P_D):
For T_A = -55°C to +100°C 500mW
For T_A = +100°C to +125°C ..... Derate Linearity at 12mW/°C to 200mW
DEVICE DISSIPATION PER OUTPUT TRANSISTOR
FOR T_A = FULL PACKAGE-TEMPERATURE RANGE (All Package Types) 100mW
OPERATING-TEMPERATURE RANGE (T_A) ..... -55°C to +125°C
STORAGE TEMPERATURE RANGE (T_{stg}) ..... -65°C to +150°C
LEAD TEMPERATURE (DURING SOLDERING):
At distance 1/16 ± 1/32 inch (1.59 ± 0.79mm) from case for 10s max ..... +265°C

TRUTH TABLES

Recommended Operating Conditions T_A=25°C
For maximum reliability, nominal operating conditions should be selected so that operation is always within the following ranges.

Characteristic	V_{DD} (V)	Min.	Max.	Units
Supply-Voltage Range (T_A = Full Package Temperature Range)	–	3	18	V
SET or RESET Pulse Width, t_W	5	160	–	ns
	10	80	–	
	15	40	–	

STATIC ELECTRICAL CHARACTERISTICS

CHARACTERISTIC	CONDITIONS			LIMITS AT INDICATED TEMPERATURES (°C)							UNITS
								+25			
	V_O (V)	V_{IN} (V)	V_{DD} (V)	−55	−40	+85	+125	Min.	Typ.	Max.	
Quiescent Device Current, I_{DD} Max.	–	0,5	5	1	1	30	30	–	0.02	1	μA
	–	0,10	10	2	2	60	60	–	0.02	2	
	–	0,15	15	4	4	120	120	–	0.02	4	
	–	0,20	20	20	20	600	600	–	0.04	20	
Output Low (Sink) Current I_{OL} Min.	0.4	0,5	5	0.64	0.61	0.42	0.36	0.51	1	–	mA
	0.5	0,10	10	1.6	1.5	1.1	0.9	1.3	2.6	–	
	1.5	0,15	15	4.2	4	2.8	2.4	3.4	6.8	–	
Output High (Source) Current, I_{OH} Min.	4.6	0,5	5	−0.64	−0.61	−0.42	−0.36	−0.51	−1	–	
	2.5	0,5	5	−2	−1.8	−1.3	−1.15	−1.6	−3.2	–	
	9.5	0,10	10	−1.6	−1.5	−1.1	−0.9	−1.3	−2.6	–	
	13.5	0,15	15	−4.2	−4	−2.8	−2.4	−3.4	−6.8	–	
Output Voltage: Low-Level, V_{OL} Max.	–	0,5	5	0.05				–	0	0.05	V
	–	0,10	10	0.05				–	0	0.05	
	–	0,15	15	0.05				–	0	0.05	
Output Voltage: High-Level, V_{OH} Min.	–	0,5	5	4.95				4.95	5	–	
	–	0,10	10	9.95				9.95	10	–	
	–	0,15	15	14.95				14.95	15	–	
Input Low Voltage, V_{IL} Max.	0.5, 4.5	–	5	1.5				—	—	1.5	V
	1, 9	–	10	3				—	—	3	
	1.5,13.5	–	15	4				—	—	4	
Input High Voltage, V_{IH} Min.	0.5, 4.5	–	5	3.5				3.5	—	—	
	1, 9	–	10	7				7	—	—	
	1.5, 3.5	–	15	11				11	—	—	
Input Current I_{IN} Max.	–	0,18	18	±0.1	±0.1	±1	±1	–	$\pm 10^{-5}$	±0.1	μA
3-State Output Leakage Current I_{OUT} Max.	0,18	0,18	18	±0.4	±0.4	±12	±12	–	$\pm 10^{-4}$	±0.4	μA

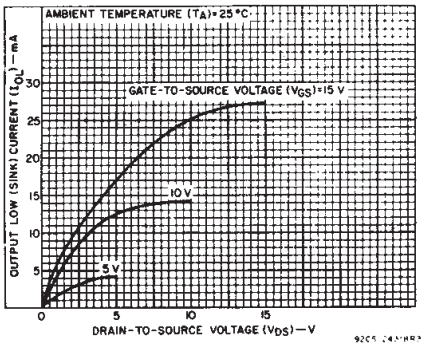


Fig. 2 — Typical output low (sink) current characteristics.

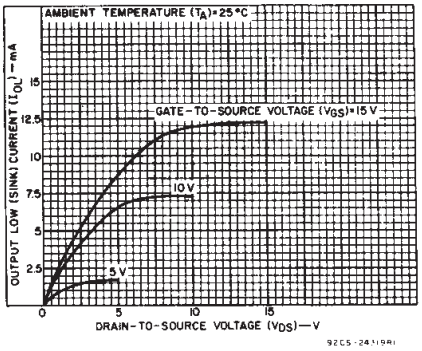


Fig. 3 — Minimum output low (sink) current characteristics.

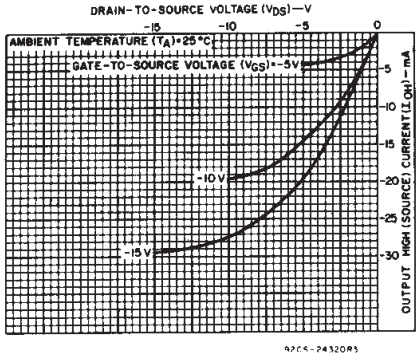


Fig. 4 — Typical output high (source) current characteristics.

DYNAMIC ELECTRICAL CHARACTERISTICS *at T_A = 25° C; Input t_r, t_f = 20 ns, C_L = 50 pF, R_L = 200 KΩ*

CHARACTERISTIC	V_{DD} (V)	LIMITS ALL TYPES TYP.	LIMITS ALL TYPES MAX.	UNITS
Propagation Delay Time: t_{PHL}, t_{PLH} SET or RESET to Q	5	150	300	ns
	10	70	140	
	15	50	100	
3-State Propagation Delay Time: ENABLE to Q t_{PHZ}, t_{PZH}	5	115	230	ns
	10	55	110	
	15	40	80	
t_{PLZ}, t_{PZL}	5	90	180	ns
	10	50	100	
	15	35	70	
Transition Time: t_{THL}, t_{TLH}	5	100	200	ns
	10	50	100	
	15	40	80	
Minimum SET or RESET Pulse Width, t_W	5	80	160	ns
	10	40	80	
	15	20	40	
Input Capacitance, (Any Input) C_{IN}	–	5	7.5	pF

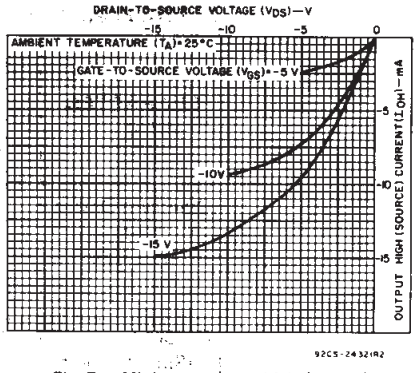


Fig. 5 – Minimum output high (source) current characteristics.

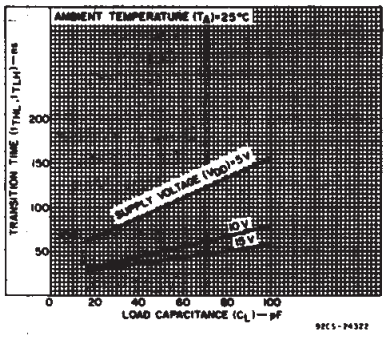


Fig. 6 – Typical transition time vs. load capacitance.

TEST CIRCUITS

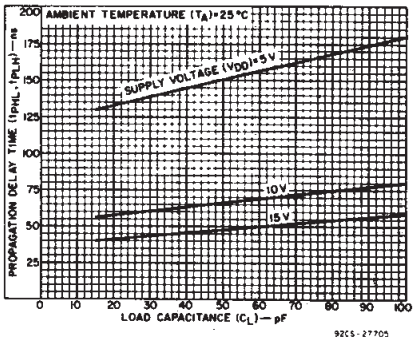


Fig. 7 – Typical propagation delay time vs. load capacitance—SET, RESET to Q, $\overline{Q}$.

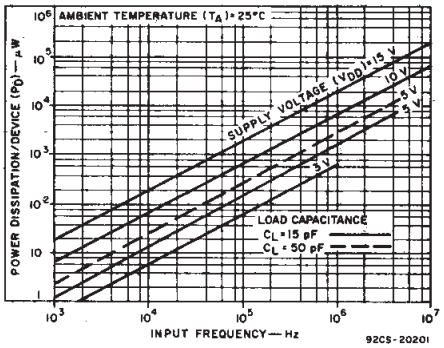


Fig. 8 – Typical power dissipation vs. frequency.

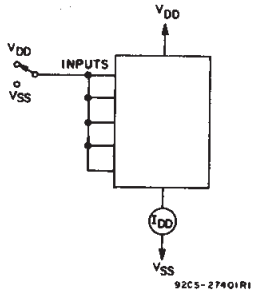


Fig. 9 – Quiescent device current.

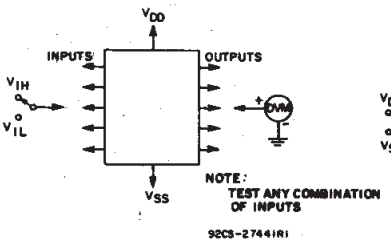


Fig. 10 – Input voltage.

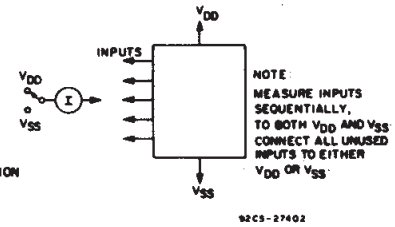


Fig. 11 – Input current.

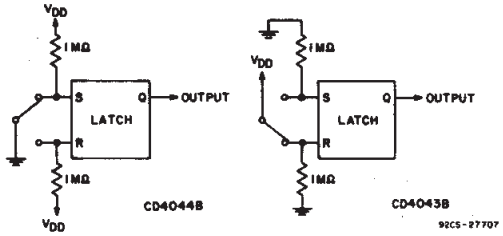


Fig. 12 – Switch bounce eliminator.